Photo Modules for PCM Remote Control Systems

Available types for different carrier frequencies

<table>
<thead>
<tr>
<th>Type</th>
<th>fo</th>
<th>Type</th>
<th>fo</th>
</tr>
</thead>
<tbody>
<tr>
<td>TSOP1730</td>
<td>30 kHz</td>
<td>TSOP1733</td>
<td>33 kHz</td>
</tr>
<tr>
<td>TSOP1736</td>
<td>36 kHz</td>
<td>TSOP1737</td>
<td>36.7 kHz</td>
</tr>
<tr>
<td>TSOP1738</td>
<td>38 kHz</td>
<td>TSOP1740</td>
<td>40 kHz</td>
</tr>
<tr>
<td>TSOP1756</td>
<td>56 kHz</td>
<td></td>
<td></td>
</tr>
</tbody>
</table>

Description

The TSOP17.. – series are miniaturized receivers for infrared remote control systems. PIN diode and preamplifier are assembled on lead frame, the epoxy package is designed as IR filter. The demodulated output signal can directly be decoded by a microprocessor. TSOP17.. is the standard IR remote control receiver series, supporting all major transmission codes.

Features

- Photo detector and preamplifier in one package
- Internal filter for PCM frequency
- Improved shielding against electrical field disturbance
- TTL and CMOS compatibility
- Output active low
- Low power consumption
- High immunity against ambient light
- Continuous data transmission possible (up to 2400 bps)
- Suitable burst length ≥10 cycles/burst

Block Diagram
**Absolute Maximum Ratings**

\( T_{\text{amb}} = 25^\circ \text{C} \)

<table>
<thead>
<tr>
<th>Parameter</th>
<th>Test Conditions</th>
<th>Symbol</th>
<th>Value</th>
<th>Unit</th>
</tr>
</thead>
<tbody>
<tr>
<td>Supply Voltage (Pin 2)</td>
<td></td>
<td>( V_S )</td>
<td>–0.3...6.0</td>
<td>V</td>
</tr>
<tr>
<td>Supply Current (Pin 2)</td>
<td></td>
<td>( I_S )</td>
<td>5</td>
<td>mA</td>
</tr>
<tr>
<td>Output Voltage (Pin 3)</td>
<td></td>
<td>( V_O )</td>
<td>–0.3...6.0</td>
<td>V</td>
</tr>
<tr>
<td>Output Current (Pin 3)</td>
<td></td>
<td>( I_O )</td>
<td>5</td>
<td>mA</td>
</tr>
<tr>
<td>Junction Temperature</td>
<td></td>
<td>( T_J )</td>
<td>100</td>
<td>°C</td>
</tr>
<tr>
<td>Storage Temperature Range</td>
<td></td>
<td>( T_{\text{stg}} )</td>
<td>–25...+85</td>
<td>°C</td>
</tr>
<tr>
<td>Operating Temperature Range</td>
<td></td>
<td>( T_{\text{amb}} )</td>
<td>–25...+85</td>
<td>°C</td>
</tr>
<tr>
<td>Power Consumption</td>
<td>( (T_{\text{amb}} \leq 85 ^\circ \text{C}) )</td>
<td>( P_{\text{tot}} )</td>
<td>50</td>
<td>mW</td>
</tr>
<tr>
<td>Soldering Temperature</td>
<td>t \leq 10 \text{ s, } 1 \text{ mm from case}</td>
<td>( T_{\text{sd}} )</td>
<td>260</td>
<td>°C</td>
</tr>
</tbody>
</table>

**Basic Characteristics**

\( T_{\text{amb}} = 25^\circ \text{C} \)

<table>
<thead>
<tr>
<th>Parameter</th>
<th>Test Conditions</th>
<th>Symbol</th>
<th>Min</th>
<th>Typ</th>
<th>Max</th>
<th>Unit</th>
</tr>
</thead>
<tbody>
<tr>
<td>Supply Current (Pin 2)</td>
<td>( V_S = 5 \text{ V, } E_V = 0 )</td>
<td>( I_{SD} )</td>
<td>0.4</td>
<td>0.6</td>
<td>1.5</td>
<td>mA</td>
</tr>
<tr>
<td></td>
<td>( V_S = 5 \text{ V, } E_V = 40 \text{ klx, sunlight} )</td>
<td>( I_{SH} )</td>
<td>1.0</td>
<td></td>
<td></td>
<td>mA</td>
</tr>
<tr>
<td>Supply Voltage (Pin 2)</td>
<td>( V_S )</td>
<td></td>
<td>4.5</td>
<td>5.5</td>
<td></td>
<td>V</td>
</tr>
<tr>
<td>Transmission Distance</td>
<td>( E_V = 0, \text{ test signal see fig.7, } ) IR diode TSAL6200, ( I_F = 400 \text{ mA} )</td>
<td>( d )</td>
<td>35</td>
<td></td>
<td></td>
<td>m</td>
</tr>
<tr>
<td>Output Voltage Low (Pin 3)</td>
<td>( I_{OSL} = 0.5 \text{ mA, } E_e = 0.7 \text{ mW/m}^2, f = f_o, t_p/T = 0.4 )</td>
<td>( V_{OSL} )</td>
<td>250</td>
<td></td>
<td></td>
<td>mV</td>
</tr>
<tr>
<td>Irradiance (30 – 40 kHz)</td>
<td>Pulse width tolerance: ( t_{pi} - 5/f_o &lt; t_{po} &lt; t_{pi} + 6/f_o ), test signal (see fig.7)</td>
<td>( E_{e \text{ min}} )</td>
<td>0.35</td>
<td>0.5</td>
<td></td>
<td>mW/m(^2)</td>
</tr>
<tr>
<td>Irradiance (56 kHz)</td>
<td>Pulse width tolerance: ( t_{pi} - 5/f_o &lt; t_{po} &lt; t_{pi} + 6/f_o ), test signal (see fig.7)</td>
<td>( E_{e \text{ min}} )</td>
<td>0.4</td>
<td>0.6</td>
<td></td>
<td>mW/m(^2)</td>
</tr>
<tr>
<td>Irradiance</td>
<td>( t_{pi} - 5/f_o &lt; t_{po} &lt; t_{pi} + 6/f_o )</td>
<td>( E_{e \text{ max}} )</td>
<td>30</td>
<td></td>
<td></td>
<td>W/m(^2)</td>
</tr>
<tr>
<td>Directivity</td>
<td>Angle of half transmission distance</td>
<td>( \varphi_{1/2} )</td>
<td>±45</td>
<td></td>
<td></td>
<td>deg</td>
</tr>
</tbody>
</table>

**Application Circuit**

* recommended to suppress power supply disturbances

**) The output voltage should not be hold continuously at a voltage below 3.3V by the external circuit.
Suitable Data Format

The circuit of the TSOP17.. is designed in that way that unexpected output pulses due to noise or disturbance signals are avoided. A bandpass filter, an integrator stage and an automatic gain control are used to suppress such disturbances. The distinguishing mark between data signal and disturbance signal are carrier frequency, burst length and duty cycle.

The data signal should fulfill the following condition:

- Carrier frequency should be close to center frequency of the bandpass (e.g. 38kHz).
- Burst length should be 10 cycles/burst or longer.
- After each burst which is between 10 cycles and 70 cycles a gap time of at least 14 cycles is necessary.
- For each burst which is longer than 1.8ms a corresponding gap time is necessary at some time in the data stream. This gap time should have at least same length as the burst.
- Up to 1400 short bursts per second can be received continuously.


When a disturbance signal is applied to the TSOP17.. it can still receive the data signal. However the sensitivity is reduced to that level that no unexpected pulses will occur.

Some examples for such disturbance signals which are suppressed by the TSOP17.. are:

- DC light (e.g. from tungsten bulb or sunlight)
- Continuous signal at 38kHz or at any other frequency
- Signals from fluorescent lamps with electronic ballast (an example of the signal modulation is in the figure below).

IR Signal from Fluorescent Lamp with low Modulation
Typical Characteristics \((T_{\text{amb}} = 25^\circ\text{C}\) unless otherwise specified)
Optical Test Signal

(VR diode TSAL6200, \( I_P = 0.4 \text{ A}, 30 \text{ pulses}, f = f_0, T = 10 \text{ ms} \))

\[
t_\text{pi} * T
\]

* \( t_\text{pi} \geq 10/f_0 \) is recommended for optimal function

Output Signal

1) \( 7/f_0 \leq t_\text{p} < 15/f_0 \)
2) \( t_\text{po} = t_\text{pi} \leq 6/f_0 \)

| \( t_\text{pi} \) | \( t_\text{po} \)
|---|---|
| \( 7/f_0 \) | \( 6/f_0 \)

Figure 7. Output Function

Optical Test Signal

\[
600 \mu s \quad 600 \mu s
\]

\( T = 60 \text{ ms} \)

Output Signal, (see Fig. 10)

\[
V_\text{O} \\
V_\text{OH} \\
V_\text{OL}
\]

\( T_{\text{on}}, T_{\text{off}} \)

Figure 8. Output Function

Output Pulse Diagram

\( T_{\text{on}}, T_{\text{off}} \)

\( \lambda = 950 \text{ nm} \), optical test signal, fig. 8

Figure 10. Output Pulse Diagram

Supply Current vs. Ambient Temperature

\( T_{\text{amb}} \)

\( V_s = 5 \text{ V} \)

Figure 11. Supply Current vs. Ambient Temperature

Max. Envelope Duty Cycle vs. Burstlength

\( B_{\text{urst}} \) [number of cycles/burst]

Figure 9. Max. Envelope Duty Cycle vs. Burstlength

Relative Spectral Sensitivity vs. Wavelength

\( \lambda \) [nm]

Figure 12. Relative Spectral Sensitivity vs. Wavelength
Figure 13. Vertical Directivity $\varphi_y$

Figure 14. Horizontal Directivity $\varphi_x$

Dimensions in mm

Center of sensitive area

Area not plane

Technical drawings according to DIN specifications

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It is the policy of Vishay Semiconductor GmbH to

1. Meet all present and future national and international statutory requirements.

2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.


2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA


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